Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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RQK0604IGDQA

Silicon N Channel MOS FET Power Switching

REJ03G1496-0100 Rev.1.00 Jan 15, 2007

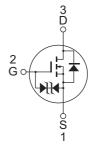
Features

- Low on-resistance $R_{DS(on)} = 111 \ m\Omega \ typ. (at \ V_{GS} = 4.5 \ V, \ I_D = 1 \ A)$
- Low drive current
- High speed switching
- $V_{DSS} \ge 60 \text{ V}$ and capable of 2.5 V gate drive

Outline

RENESAS Package code: PLSP0003ZB-A (Package name: MPAK)





1. Source

Gate
 Drain

Note: Marking is "IG".

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	60	V
Gate to source voltage	V _{GSS}	±12	V
Drain current	I _D	2	А
Drain peak current	I _{D(pulse)} Note1	8	А
Body - drain diode reverse drain current	I _{DR}	2	Α
Channel dissipation	Pch Note2	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, Duty cycle \leq 1%

2. When using the glass epoxy board (FR-4 $40 \times 40 \times 1$ mm)

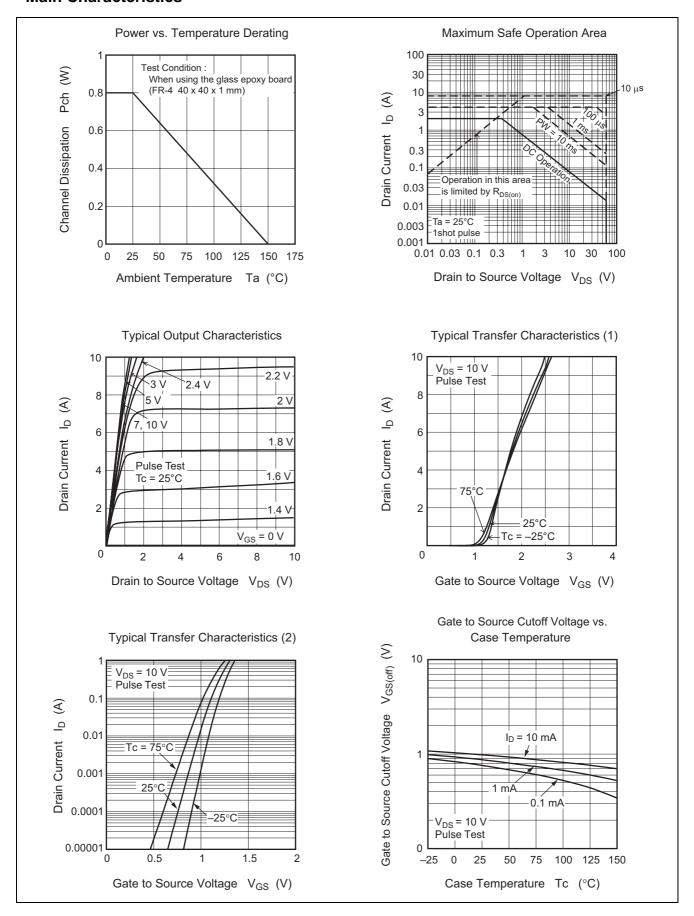
Electrical Characteristics

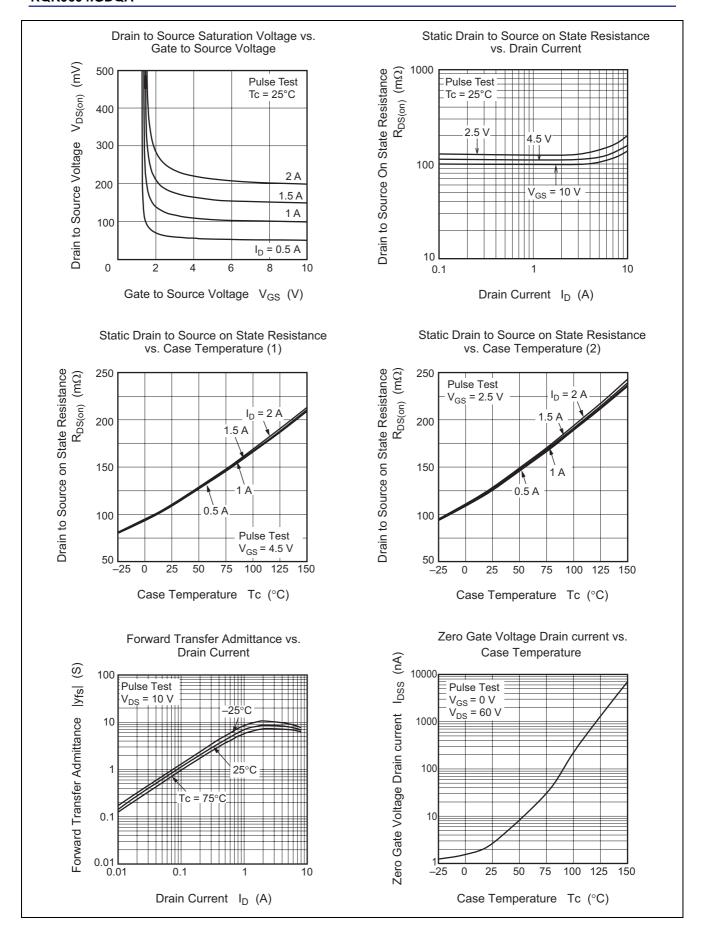
 $(Ta = 25^{\circ}C)$

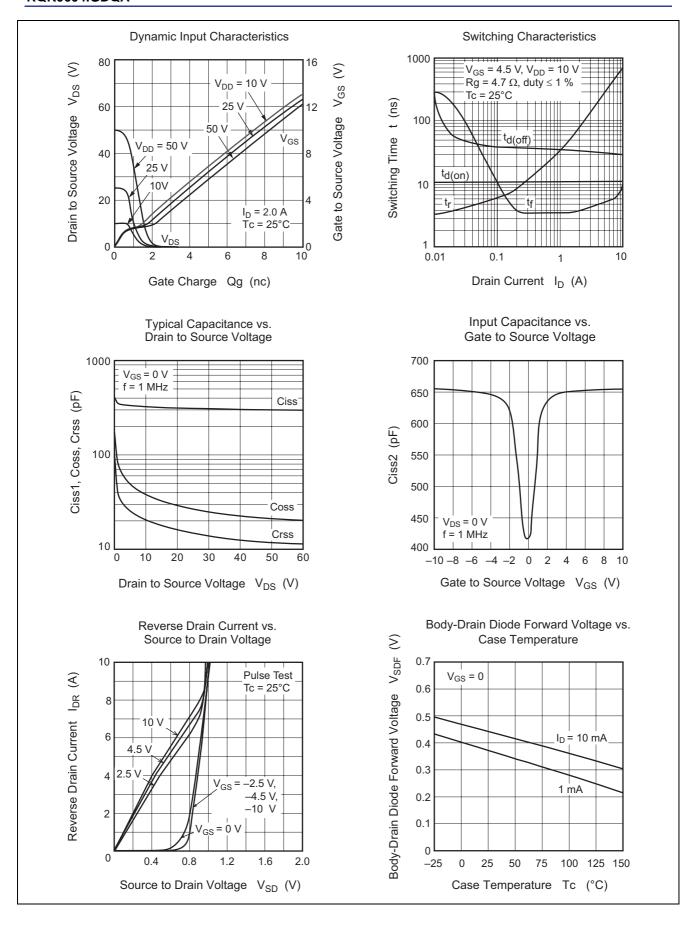
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	+12	_	_	V	$I_G = +100 \mu\text{A}, V_{DS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	-12	_	_	V	$I_G = -100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	+10	μΑ	$V_{GS} = +10 \text{ V}, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	-10	μΑ	$V_{GS} = -10 \text{ V}, V_{DS} = 0$
Drain to source leak current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	0.4	_	1.4	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Drain to source on state resistance	R _{DS(on)}	_	111	144	mΩ	$I_D = 1 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
Drain to source on state resistance	R _{DS(on)}	1	129	180	mΩ	$I_D = 1 \text{ A}, V_{GS} = 2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y _{fs}	3	6	_	S	$I_D = 1 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss	_	320	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	38	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	20	_	pF	f = 1 MHz
Turn - on delay time	t _{d(on)}	_	12	_	ns	I _D = 1 A
Rise time	t _r	_	35	_	ns	$V_{GS} = 10 \text{ V}$
Turn - off delay time	t _{d(off)}	_	36	_	ns	$R_L = 10 \Omega$
Fall time	t _f	_	3.7	_	ns	$Rg = 4.7 \Omega$
Total gate charge	Qg	_	3.4	_	nC	V _{DD} = 10 V
Gate to Source charge	Qgs		0.6	_	nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd		1.0	_	nC	I _D = 2 A
Body - drain diode forward voltage	V_{DF}	_	0.8	_	V	$I_F = 2 A, V_{GS} = 0^{Note3}$

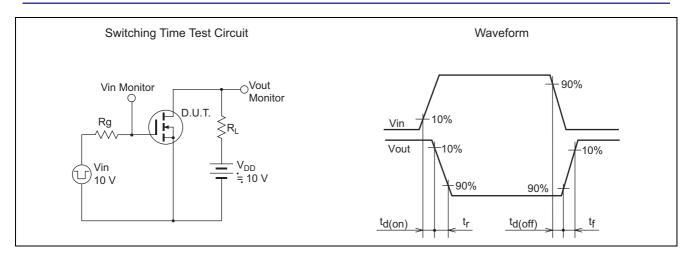
Notes: 3. Pulse test

Main Characteristics

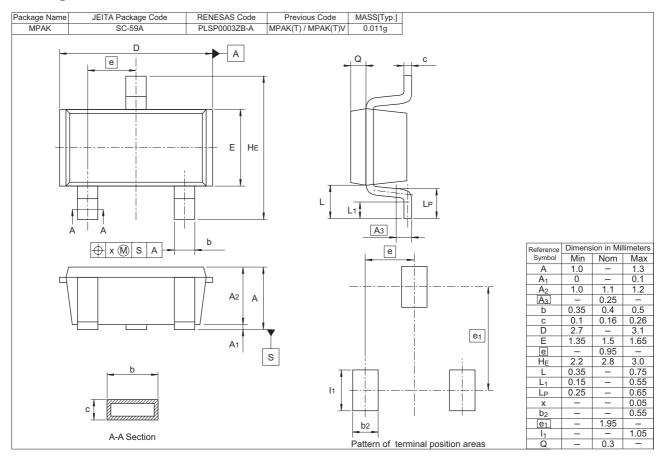








Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
RQK0604IGDQATL-E	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

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